

To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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Phase-out/Discontinued

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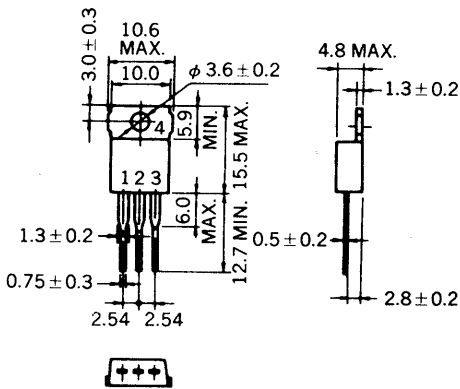
N-CHANNEL MOS FIELD EFFECT POWER TRANSISTORS 2SK1495, 2SK1495-Z/2SK1496, 2SK1496-Z

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

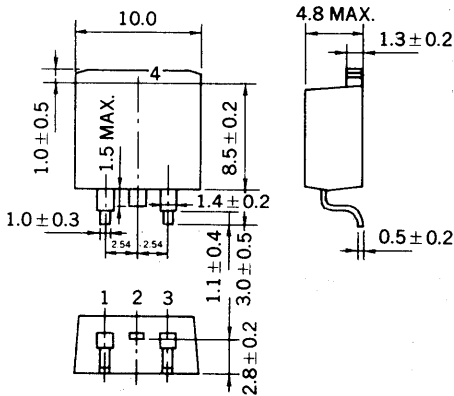
Phase-out/Discontinued

PACKAGE DIMENSIONS (Unit: mm)

2SK1495, 2SK1496

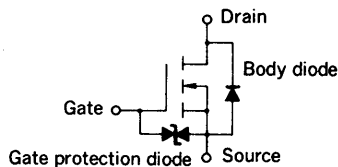


2SK1495-Z, 2SK1496-Z



PIN CONNECTIONS

1. Gate
2. Drain
3. Source
4. Fin (Drain)



DESCRIPTION

The 2SK1495/2SK1496 is N-channel MOS Field Effect Transistor designed for high voltage switching applications.

FEATURES

- Low On-state Resistance
 $R_{DS(on)} = 0.9 \Omega \text{ MAX.}/1.0 \Omega \text{ MAX.}$ ($V_{GS} = 10 \text{ V}$, $I_D = 4 \text{ A}$)
- Low C_{iss} $C_{iss} = 1060 \text{ pF TYP.}$
- Built-in G-S Gate Protection Diodes
- High Avalanche Capability Ratings

ABSOLUTE MAXIMUM RATINGS

Maximum Temperatures

Storage Temperature	T_{stg}	-55 to +150	°C
Channel Temperature	T_{ch}	150	°C MAX.

Maximum Power Dissipation

Total Power Dissipation ($T_A = 25 \text{ °C}$)	P_T	70	W
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Maximum Voltages and Currents ($T_A = 25 \text{ °C}$)

Drain to Source Voltage	V_{DSS}	450/500	V
(2SK1495/2SK1496)			
Gate to Source Voltage	V_{GSS}	±30	V
Drain Current (DC)	$I_{D(DC)}$	±7	A
Drain Current (pulse)	$I_{D(pulse)}$ *	±28	A

* $PW \leq 10 \mu s$, Duty Cycle $\leq 1 \%$

Maximum Avalanche Capability Ratings**

Single Avalanche Current	I_{AS}	10.5	A
Single Avalanche Energy	E_{AS}	206	mJ

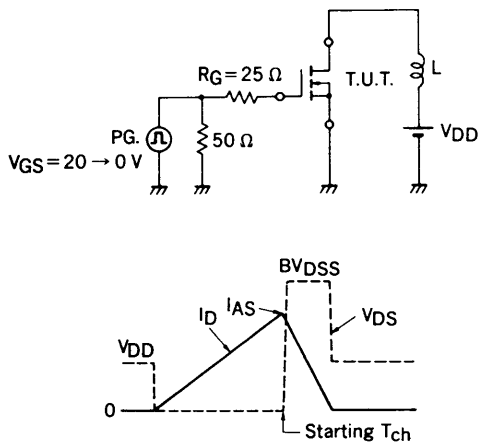
** Starting $T_{ch} = 25 \text{ °C}$, $R_G = 25 \Omega$, $V_{GS} = 20 \text{ V} \rightarrow 0$

Phase-out/Discontinued

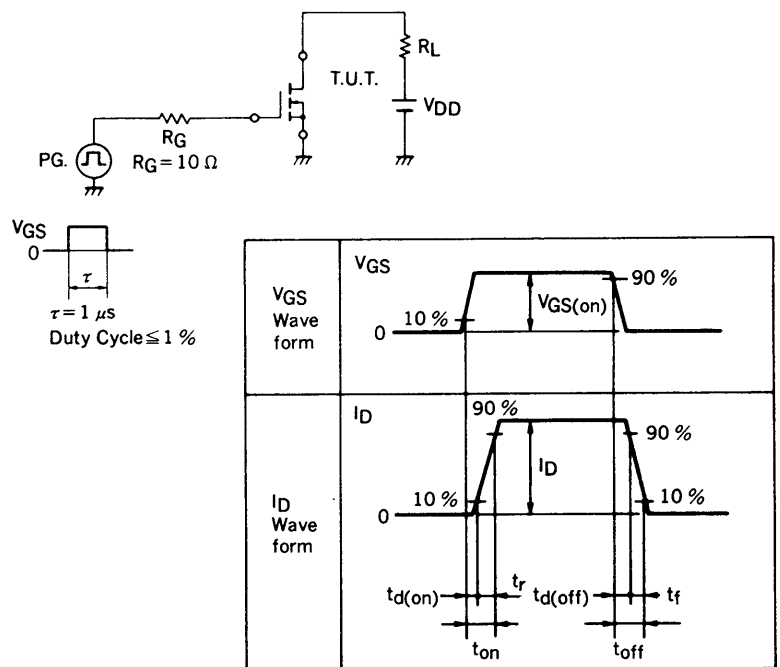
ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-state Resistance (2SK1493/2SK1494)	R _{DS(on)}		0.7/0.8	0.9/1.0	Ω	V _{GS} = 10 V, I _D = 4 A
Gate to Source Cutoff Voltage	V _{GS(off)}	2.5		3.5	V	V _{DS} = 10 V, I _D = 1 mA
Forward Transfer Admittance	y _{fs}	3.0			S	V _{DS} = 10 V, I _D = 4 A
Drain Leakage Current	I _{DSS}			100	μA	V _{DS} = 450V/500V, V _{GS} = 0
Gate to Source Leakage Current	I _{GSS}			±10	μA	V _{GS} = ±30 V, V _{DS} = 0
Input Capacitance	C _{iss}		1 060		pF	V _{DS} = 10 V
Output Capacitance	C _{oss}		340		pF	V _{GS} = 0
Reverse Transfer Capacitance	C _{rss}		150		pF	f = 1 MHz
Turn-On Delay Time	t _{d(on)}		20		ns	V _{GS} = 10 V
Rise Time	t _r		30		ns	V _{DD} = 150 V
Turn-Off Delay Time	t _{d(off)}		70		ns	I _D = 4 A, R _G = 10 Ω
Fall Time	t _f		20		ns	R _L = 37.5 Ω
Total Gate Charge	Q _G		36		nC	V _{GS} = 10 V
Gate to Source Charge	Q _{GS}		7		nC	I _D = 7 A
Gate to Drain Charge	Q _{GD}		21		nC	V _{DD} = 400 V
Diode Forward Voltage	V _{F(S-D)}		1.0		V	I _F = 7 A, V _{GS} = 0
Reverse Recovery Time	t _{rr}		420		ns	I _F = 7 A
Reverse Recovery Charge	Q _{rr}		2.1		μC	di/dt = 50 A/μs

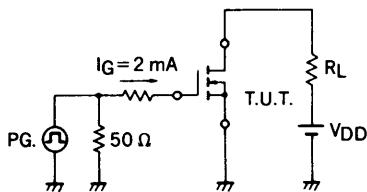
Test Circuit 1: Avalanche Capability



Test Circuit 2: Switching Time



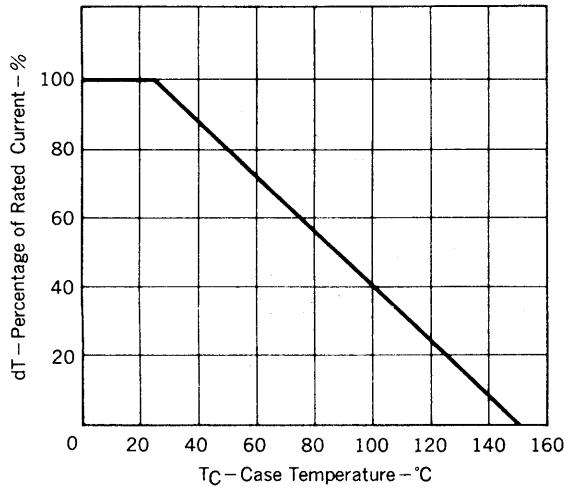
Test Circuit 3: Gate Charge



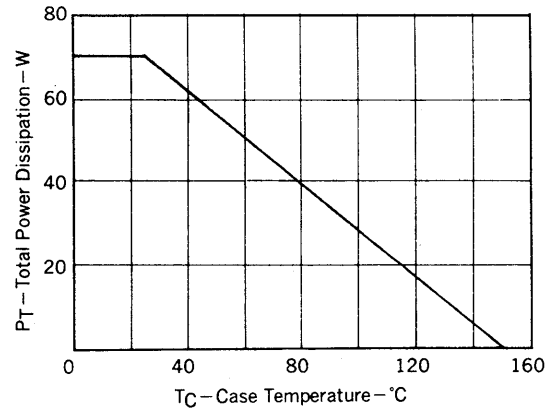
Phase-out/Discontinued

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

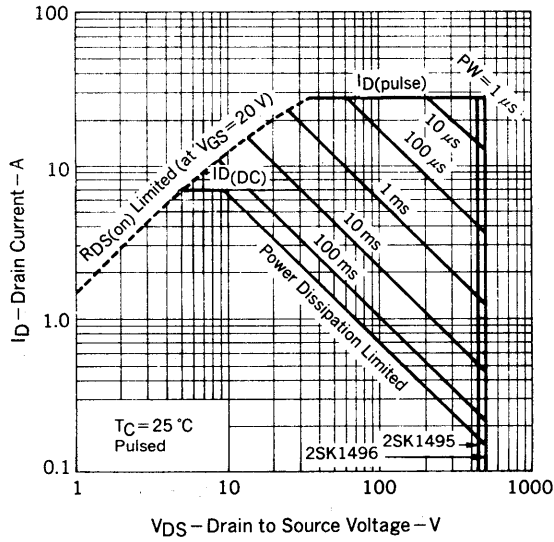
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



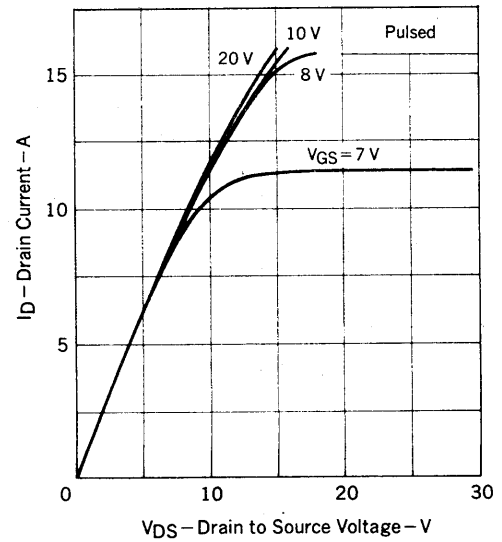
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



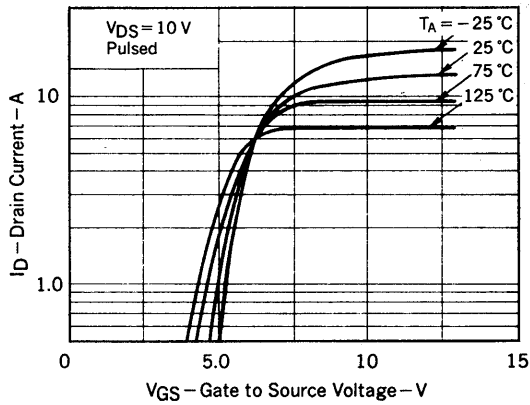
FORWARD BIAS SAFE OPERATING AREA



DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

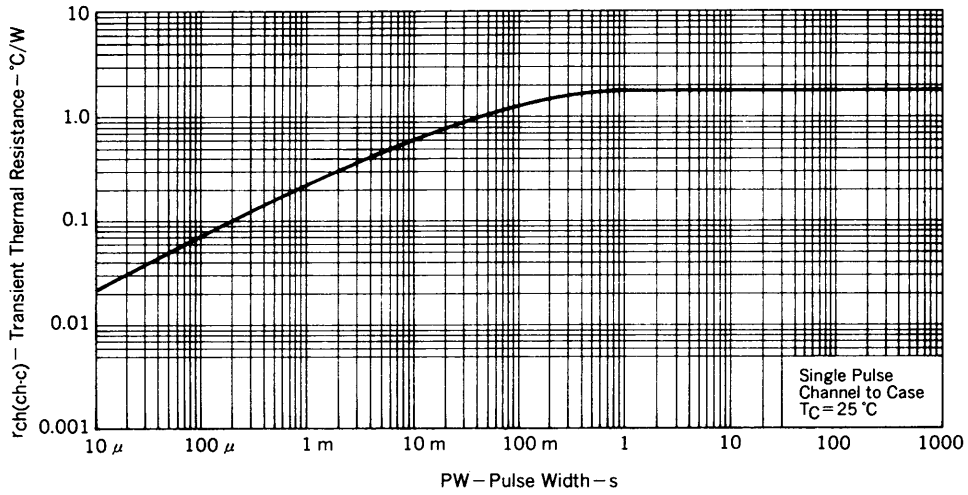


TRANSFER CHARACTERISTICS

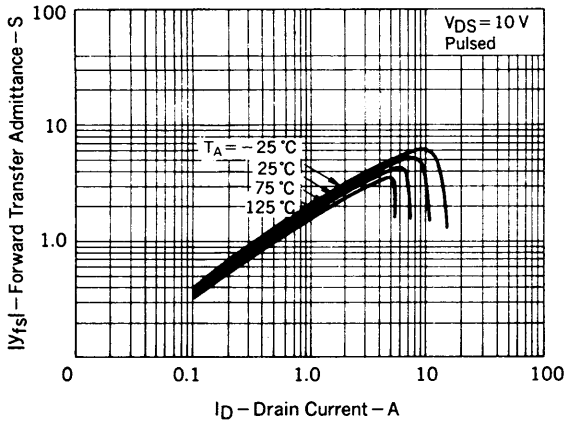


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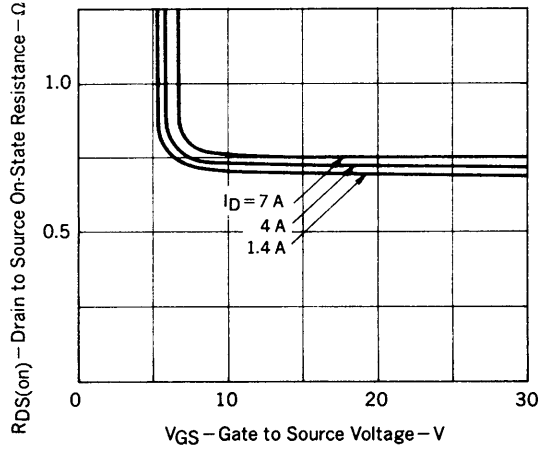
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



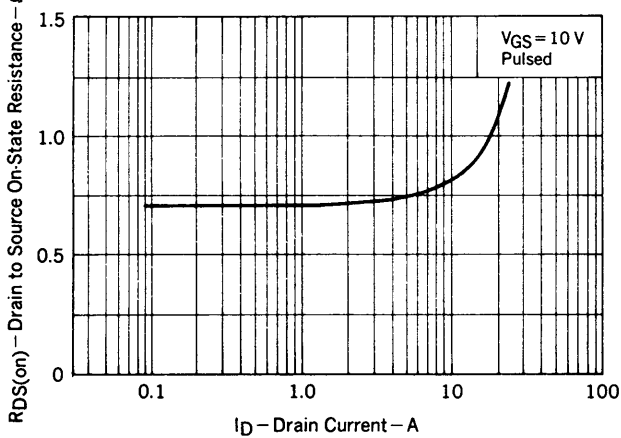
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



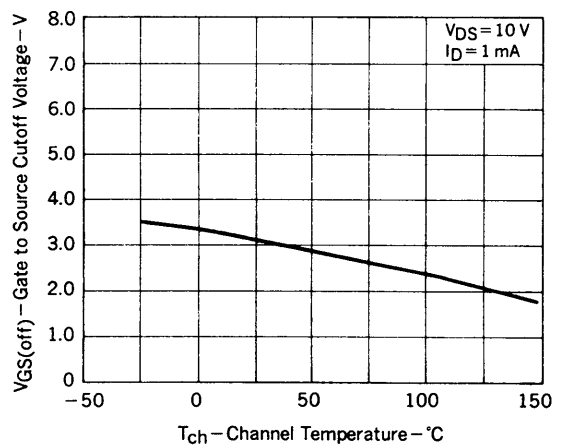
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



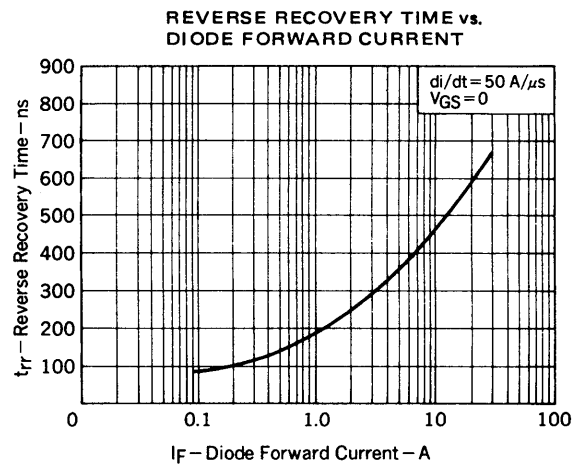
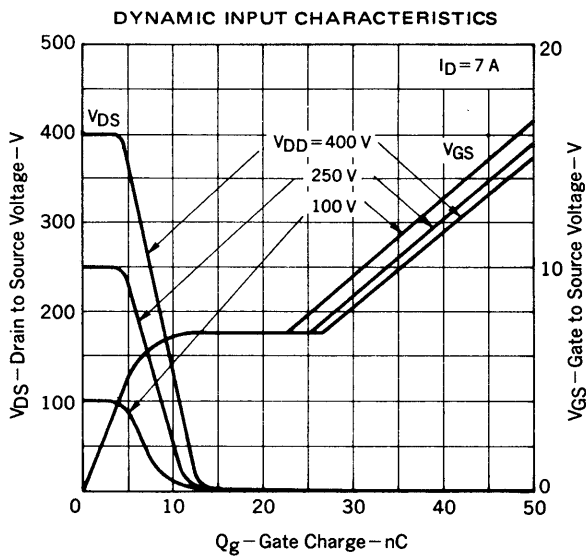
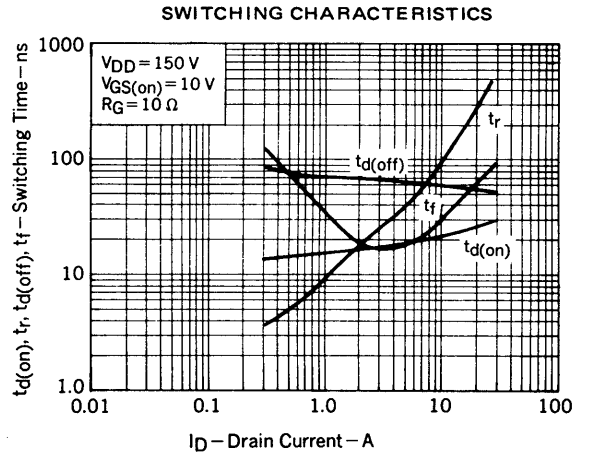
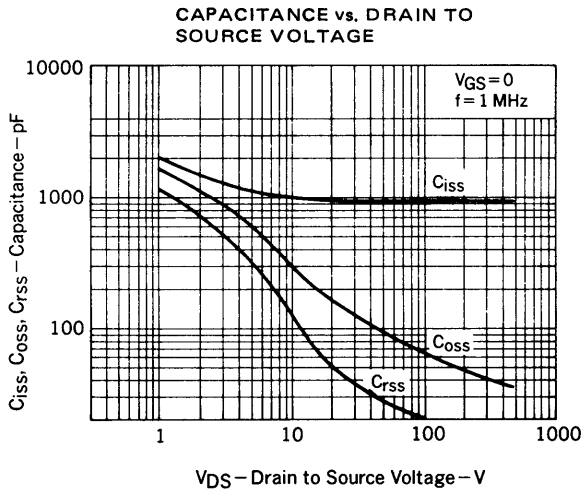
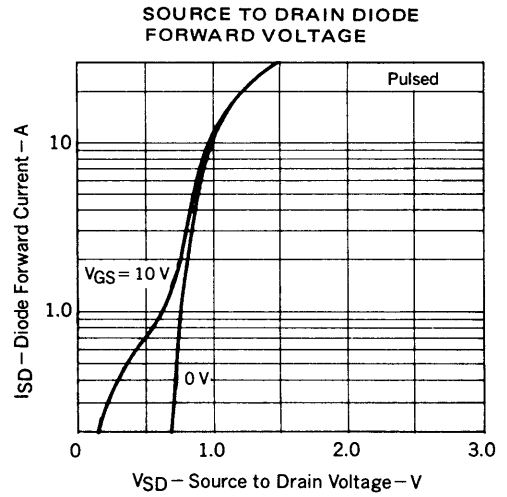
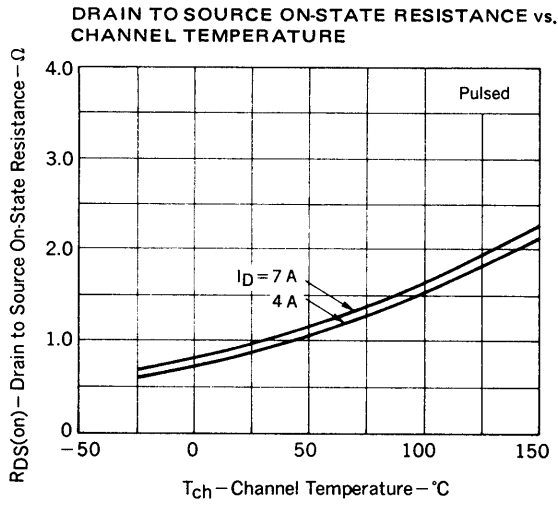
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE

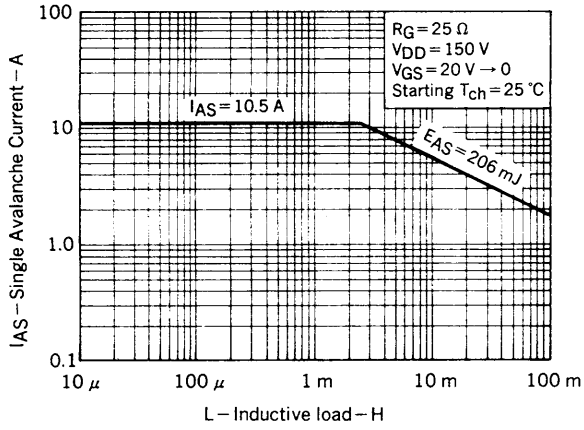


Phase-out/Discontinued

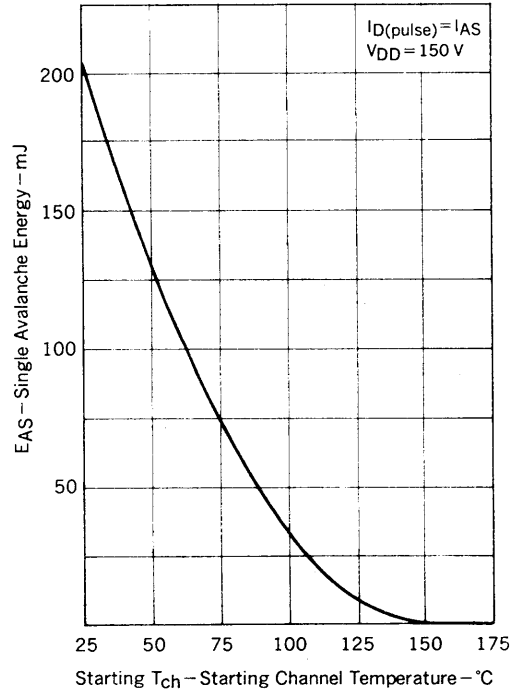


Phase-out/Discontinued

SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



SINGLE AVALANCHE ENERGY vs. STARTING CHANNEL TEMPERATURE



Phase-out/Discontinued**REFERENCE**

Application note name	No.
Safe operating area of Power MOS FET.	TEA-1037
Application circuit using Power MOS FET.	TEA-1035
Guide to quality assurance for semiconductor device.	MEI-1202
Power MOS FET features and application switching power supply	TEA-1034

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Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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